



MOSAID Technologies Incorporated

FOR IMMEDIATE RELEASE

**JUDGE DENIES SAMSUNG MOTION
FOR MORE DEFINITE STATEMENT OF CLAIM**

OTTAWA, Ontario, Canada – January 3, 2002 – MOSAID Technologies Incorporated (TSE: MSD) announced today an update in its ongoing patent litigation against Samsung Electronics Co., Ltd. and several of its U.S.-based affiliates.

MOSAID received notice today that United States Magistrate Judge G. Donald Haneke has issued an order in the United States District Court for the District of New Jersey denying Samsung's motion for a more definite statement of the Complaint in this action.

MOSAID commenced litigation against Samsung Electronics Co., Ltd. and several of its U.S.-based affiliates on September 13, 2001, for infringement of seven of MOSAID's United States patents relating to Dynamic Random Access Memory (DRAM) circuit inventions.

About MOSAID

MOSAID Technologies Incorporated is an independent semiconductor company operating through three divisions:

- *Semiconductor* – a fabless developer of classification chips for the networking market
- *Intellectual Property* – a licensor of intellectual property to semiconductor manufacturers worldwide
- *Systems* – the leading supplier of engineering memory test and analysis systems to memory manufacturers, foundries and fabless chip companies.

Founded in 1975, MOSAID is based in Ottawa, Ontario, Canada, with offices in Austin, Texas; Santa Clara, California; Newcastle-upon-Tyne, U.K; and Tokyo, Japan. For more information, visit the Company's web site at www.mosaid.com.

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For more information, please contact:

Investor Inquiries

David Ward
Director, Communications and Investor Relations
613-599-9539 x1205
ward@mosaid.com

Media Inquiries

Marisa Marzano
Senior Communications Specialist
613-599-9539 x1228
marzano@mosaid.com